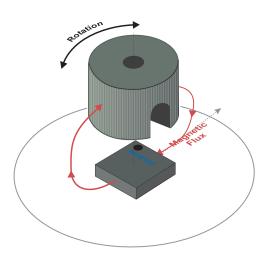
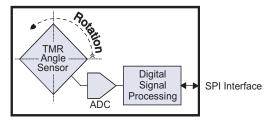


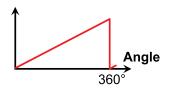
# **ASR002 Smart TMR Angle Sensor**



# **Block Diagram**



# **Transfer Function**



# **Features**

- Rotational speeds to 375,000 RPM
- 3.3 volt or 5 volt compatible four-wire SPI interface
- Robust airgap and misalignment tolerances
- Factory calibrated
- Ultraminiature 2.5 x 2.5 x 0.8 mm TDFN6 package

# **Key Specifications**

- 0.1° resolution
- ±0.2° repeatability
- Robust 6 to 20 mT (60 to 200 Oe) field operating range
- Fast 12.5 kSps sample rate
- Flexible 2.2 to 3.6 V supply range
- Low 4 mA typical supply current
- Full –40 °C to 125 °C operating range

## **Applications**

- Rotary encoders
- Robotics
- Motor control
- Automotive applications
- Internet of Things (IoT) end nodes

#### **Description**

ASR002 TMR Smart Angle Sensors provide a precise digital angle measurement over a wide range of speeds.

The sensor combines precise, low-power Tunneling Magnetoresistance (TMR) sensing elements with sophisticated digital signal processing.

The sensor is factory calibrated, with coefficients stored in internal memory.

A four-wire SPI interface provides angle data and allows setting device parameters.

The ASR002 is designed for harsh industrial or automotive environments with ESD protection, and full –40 °C to 125 °C operating temperature range.





# **Boundary Ratings**

Parameter	Min.	Max.	Units
Supply voltage	-12	4.2	Volts
Input and output voltages (MISO, MOSI, SS, SCLK)	-0.5	V <sub>cc</sub> +2.5 up to 5.8	Volts
Input current	-100	+100	mA
Storage temperature	-55	150	°C
ESD (Human Body Model)		2000	Volts
Applied magnetic field		Unlimited	Tesla





# Operating Specifications ( $T_{min}$ to $T_{max}$ ; 2.2 < $V_{DD}$ < 3.6 V unless otherwise stated)

Operating temperature	Max.	Units	<b>Test Condition</b>
Supply voltage         V <sub>DD</sub> 2.2           Supply current         I <sub>DD</sub> 4           Power-on Reset supply voltage         V <sub>POR</sub> 1.4           Brown-out power supply voltage         V <sub>ROR</sub> 0.75         1           Start-up time         T <sub>STA</sub> 15           Magnetics           Applied magnetic field strength         H         20         12           Applied magnetic field strength         H         20         12           Applied magnetic field strength         H         60         120           Accuracy and Repeatability           Angular resolution         δ         0.1           Angular accuracy, fixed bias¹         ε           Angular accuracy, fixed bias¹         ε           Angular accuracy, fixed bias¹         ε           Angular accuracy, fixed bias¹           Speed           Speed           Speed           Speed           Speed           Speed           Sample rate         12.5           SPI Bus Characteristics	125	°C	
Supply current	3.6	V	
Power-on Reset supply voltage   V_POWE   T.4	6	mA	Max. at $V_{DD} = 3.6V$
Brown-out power supply voltage   V <sub>BOR</sub>   0.75   1		V	DD
Start-up time         T <sub>STA</sub> 15           Magnetics         20         12           Applied magnetic field strength         H         20         12           Accuracy and Repeatability         Both Companies         0.1           Angular resolution         δ         0.1           Angular hysteresis         J         ±0.2           Repeatability         ±0.2         ±0.2           Angular accuracy, fixed bias¹         ε         Angular accuracy, fixed bias²           Speed         5         5         5         5         5         5         6         5         1         2 <th< td=""><td>1.36</td><td>V</td><td></td></th<>	1.36	V	
Applied magnetic field strength		ms	
Applied magnetic field strength			
Applied magnetic field strength	20	mT	
Angular resolution	200	Oe	
Angular hysteresis			-
Repeatability			
Angular accuracy, fixed bias¹  Angular accuracy, variable bias²  Speed  Sample rate  Sample rate  Sample rate  SPI Bus Characteristics  Bus voltage  Low level input threshold voltage  V <sub>IL</sub> Low level input threshold voltage  V <sub>IL</sub> Low level output current  I/O Lour 3  I/O capacitance  SPI Setup and Hold Timing  Data transfer rate  DR  SCLK Rise time  SCLK fall time  SCLK fall time  SCLK fall time  t <sub>CH</sub> SCLK setup  SS to SCLK setup  SS to SCLK setup  SS to MISO valid  SS to MISO tri-state  SCLK to MOSI hold time  t <sub>SDD</sub> SCLK to SS hold time  t <sub>SDD</sub> SCLK to SS hold time  t <sub>SEZ</sub> RAM Timing  Address setup time  t <sub>ADDR</sub> Address setup time  t <sub>ADDR</sub> Table Address setup time  t <sub>ADDR</sub> Address setup time  t <sub>ADDR</sub> Table Address setup time  t <sub>ADDR</sub> Address setup time  t <sub>ADDR</sub> Table Address setup time  t <sub>ADDR</sub> Address setup time  t <sub>ADDR</sub> Address setup time  t <sub>ADDR</sub> Data read time  t <sub>READ</sub> Data read time  t <sub>NNVM</sub> Data write time	0.1		
Speed   Sample rate   12.5		Angular Degrees	Fixed temperature and bias <sup>1</sup>
Speed   Sample rate   12.5	±2		0 to 85°C
Sample rate	±3		−40 to 125°C
Sample rate   12.5	±6		−40 to 125°C
SPI Bus Characteristics           Bus voltage         V <sub>BUS</sub> 2.2           Low level input threshold voltage         V <sub>III</sub> 0.8           High level input threshold voltage         V <sub>III</sub> 0.8           Low level oil input threshold voltage         V <sub>III</sub> 0.8           I Spid in vertical input threshold voltage         V <sub>III</sub> 0.8           I/O capacitance         DR         3         0           SPI Setup and Hold Timing         t <sub>READ</sub> 0         0           SCLK Rise time         t <sub>READ</sub> 0         0         0           SCLK set ime         t <sub>SE</sub> 80         0 </td <td></td> <td></td> <td></td>			
Bus voltage		kSps	
$ \begin{array}{ c c c c } \hline Low level input threshold voltage & V_{IL} & 0.8 \\ \hline High level input threshold voltage & V_{IH} & \\ \hline Low level output current & I_{OL} & 3 \\ \hline I/O capacitance & C_{I/O} & \\ \hline \hline \textbf{SPI Setup and Hold Timing} \\ \hline Data transfer rate & DR & \\ \hline SCLK Rise time & t_{R} & \\ \hline SCLK fall time & t_{F} & \\ \hline SCLK low time & t_{CL} & 200 \\ \hline SCLK fall time & t_{CL} & 200 \\ \hline SCLK fall time & t_{CH} & 200 \\ \hline SS to SCLK setup & t_{SE} & 80 \\ \hline SCLK to MISO valid & t_{SDD} & \\ \hline SS to MISO tri-state & t_{SDZ} & \\ \hline SCLK to MOSI hold time & t_{SDH} & 80 \\ \hline MOSI to SCLK setup & t_{SDS} & 80 \\ \hline SCLK to SS hold time & t_{SH} & 80 \\ \hline SS to MISO valid & t_{SEZ} & \\ \hline \hline \textbf{RAM Timing} & & & & & & \\ \hline Address setup time & t_{ADDR} & 3 \\ \hline Data read time & t_{READ} & 10 \\ \hline Nonvolatile Memory Characteristics & & & & \\ \hline Data write time & t_{NVM} & 20 \\ \hline \end{array}$			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	5.5	V	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		V	
Low level output current	2.2	V	
I/O capacitance		mA	$V_{OL} = 0.4V$
Data transfer rate	10	pF	OL -
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		T T	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	2	Mbits/s	Full duplex
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	1
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	1
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	
SCLK to MISO valid $t_{SDD}$ SS to MISO tri-state $t_{SDZ}$ SCLK to MOSI hold time $t_{SDH}$ 80MOSI to SCLK setup $t_{SDS}$ 80SCLK to SS hold time $t_{SH}$ 80SS to MISO valid $t_{SEZ}$ RAM Timing $t_{ADDR}$ 3Data read time $t_{READ}$ 10Nonvolatile Memory CharacteristicsAddress setup time $t_{ADDR}$ 3Data read time $t_{READ}$ 10Data read time $t_{READ}$ 10Data write time $t_{READ}$ 10		ns	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	170	ns	See figure 7
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	170	ns	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	1
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		ns	1
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	170	ns	1
$ \begin{array}{c cccc} Address \ setup \ time & t_{ADDR} & 3 \\ Data \ read \ time & t_{READ} & 10 \\ \hline \textbf{Nonvolatile Memory Characteristics} \\ Address \ setup \ time & t_{ADDR} & 3 \\ Data \ read \ time & t_{READ} & 10 \\ Data \ write \ time & t_{NVM} & 20 \\ \hline \end{array} $	1,0	110	
		μs	
		μs	See figure 4
$ \begin{array}{cccc} \text{Data read time} & & & & & & & & & & & & \\ \text{Data write time} & & & & & & & & & & \\ \text{Data write time} & & & & & & & & & & \\ \end{array} $		μs	
Data write time t <sub>NVM</sub> 20		μs	See figure 5
		ms	
1/////		Cycles	
Package Thermal Characteristics		- Cycles	
Junction-to-ambient thermal resistance $\theta_{JA}$ 320		°C/W	
Package power dissipation 500		mW	

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# **Specification Notes:**

- 1. "Fixed Bias" means a fixed airgap within between the bias magnet and sensor so the magnitude of the magnetic field at the sensor is constant within the specified field range of the parts. The highest accuracy is obtained using fields closest to the 17.5 mT (175 Oe) factory calibration field.
- 2. "Variable Bias" means the magnitude of the magnetic field at the sensor can vary across the entire specification range.



# **ASR002 Overview**

The ASR002 is a non-contact angle sensor designed for high speed applications where size is limited. The heart of the ASR002 is a tunneling magnetoresistive (TMR) sensor. In a typical configuration, an external magnet provides a magnetic field of 6 to 20 mT (60 to 200 Oe) in the plane of the sensor, as illustrated below for a bar magnet and a diametrically-magnetized disk magnet. Factory-programmed signal conditioning is combined with a temperature sensor and digital linearization to produce high speed, accuracy, and precision in a tiny 2.5 x 2.5 mm TDFN package.

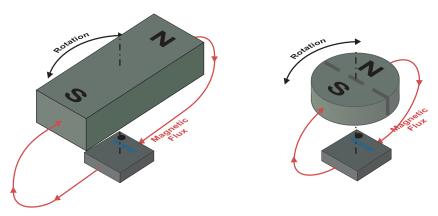


Figure 1. Sensor operation.

### **ASR002 Operation**

A detailed block diagram is shown below:

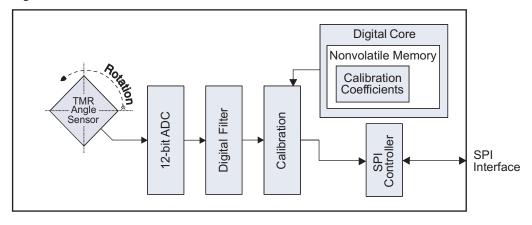


Figure 2. Detailed block diagram.

# TMR Angle Sensor Element

ASR002 sensors use unique TMR sensor elements that are inherently high speed and low noise. The digital core calculates the angle from sensor element Sine and Cosine vectors, and the raw sensor data are available from separate memory locations.

### **ADC**

The sensor output is digitized with a 12-bit ADC. The extra bits ensure precision and computational accuracy.

## Digital Filter

A first-order Infinite Impulse Response (IIR) digital filter with a programmable cutoff frequency can be used for ultralow noise if high-frequency operation is required. The factory default is the filter turned off.

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#### **Rotation Direction**

The ASR002 can provide increasing angle values for either clockwise or counterclockwise field rotations. Counterclockwise is defined as a rotating field vector through pins 1-3-4-6, and clockwise through pins 1-6-4-3. The rotation direction can be programmed using the  $\theta_{DIR}$  parameter.



Figure 3. Zero-angle reference  $(\theta_0)$  and rotation direction  $(\theta_{DIR})$ . The rotational center of the sensor is the package center.

#### Zero-Angle Reference Point

A programmable parameter  $\theta_0$  sets the zero-degree reference or angular offset. This is the angle of "discontinuity," that is, where the angle output changes from 360° to 0°. The default  $\theta_0$  value is zero for magnetic fields pointing from pin 1 to pin 6.

#### Direction and Hysteresis

The Direction output indicates direction of rotation. A hysteresis setting can be changed to prevent small changes from causing the Direction output to "chatter," especially at low speed.

## Digital Filter

The digital filter is an Infinite impulse response (IIR) weighted running average filter, which can reduce mechanical and electrical noise depending on the required speed.

The filtered output is calculated as follows:

$$\theta_n = \theta/m + [(m-1)/m]\theta_{n-1}$$

Where  $\theta$  = is the measured angle;  $\theta_n$  = the filtered angle;  $\theta_{n-1}$  is the previous value of the filtered angle; and m is a constant that determines the cutoff frequency as follows:

$$f_{CLITOFF} = f_{SAMPLF}/(2\pi \text{ m})$$

Where  $f_{\text{CUTIOFF}}$  is the filter cutoff frequency and  $f_{\text{SAMPLE}}$  is the sensor ADC sampling rate (approximately 12500/s). So for example, if m = 10, the cutoff frequency is approximately 200 Hz.

m = 1 disables filter so the output is simply updated with each sample.

#### A Simple SPI Interface

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The SPI interface is an industry standard four-wire, full-duplex 2 megabit per second connection with the sensor as the slave to an external master such as a microcontroller. SPI data (MOSI and MISO) and the Clock (SCLK) are 2.2 volt to five-volt compliant. The digital angle is the default two byte response.

The ASR002 uses an industry-standard "Mode 0" interface (data is sampled at the leading rising edge of the clock; CPOL=0 and CPHA=0). In accordance with industry standards, slave select (SS) is active-low, and bit order and byte order are from MSB to LSB.

Details are shown in the following timing diagrams:











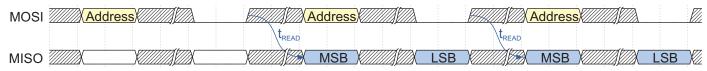


Figure 6. Continuous read.

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SPI setup and hold timing constraints are shown in Figure 7:

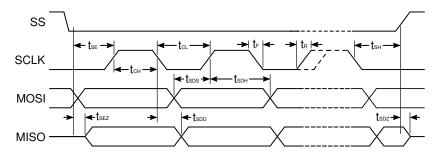


Figure 7. SPI setup and hold timing.

A schematic of a typical interface to a 3.3-volt or five-volt microcontroller is show in Figure 10.

# Straightforward Reading and Writing

The sensor is reset on a falling edge of SS. All reads and writes are initiated by the master pulling SS "LOW" and sending an eight-bit address to the ASR002 plus a second byte. The least significant bit of the second address byte indicates whether the address request is for a read or a write ("0" is a read; "1" is a write). The slave responds with two bytes of data.

As shown in figures 4 and 5, and the specification table, a 3  $\mu$ s delay ( $t_{ADDR}$ ) is needed between address bytes; 10  $\mu$ s ( $t_{READ}$ ) should be allowed before data can be read, and 20 ms ( $t_{NVM}$ ) should be allowed for writing parameters to the nonvolatile memory.

#### Reading the angle

To read the angle, the master simply writes two zero bytes for the "0" angle address, then reads the two-byte angle, which is expressed in tenths of degrees. These two-byte reads can be repeated to continuously read the angle as shown in the Figure 6 timing diagram and the code on p. 14.

# Reading and writing parameters

Reading and writing parameters are simple four-byte sequences. The master writes two bytes for the parameter address, then reads or writes two bytes for the parameter value. Illustrative code to zero the sensor by writing the offset parameter is shown on p. 15.

The number of bits in different parameters varies. Unused bits are sent as zeros by the sensor. Similarly, unused bits should be written as zeros to the sensor to avoid an out-of-range parameter that could be ignored.



# Memory Map

The ASR002 memory provides access to angle data and user-programmable parameters. The memory is accessed via SPI as described in the SPI interface section.

		Read/			
Symbol	Default	Write	Range	Address	Description
_					
T .	1	T		1	
θ			0 – 3600	0x00	In tenths of a degree
Sinθ			Approx. 1500 – 2500	0x01	Raw outputs centered at approx.
G 0	N/A	P		0.02	2048 with peak-peak amplitudes of
Cost	11///	K		0x02	approx. 1000.
Die			0 1	002	0 = decreasing angle
Dil			0 – 1	0.03	1 = increasing angle
	Us	ser-Progra	mmable Paran	neters	
			0 – 1	0x40 [bit 0]	0 → increasing CCW;
$\theta_{ m DIR}$	0				1 → increasing CW
					(see Fig. 3)
$\theta_0$	0	R/W	0 – 3600	0x41	Point at which angle is zero
				[bits 13:0]	(see Fig. 3)
m			1 – 255	0x42	$f_{\text{CUTOFF}} = f_{\text{SAMPLE}}/(2\pi \text{ m});$
	1				$f_{SAMPLE} = approx. 12.5 \text{ kSps}$
					m = 1 disables filter
ection Hysteresis $\delta_{\text{DIR}}$ 25 $0-255$		0 - 255	0. 42	Hysteresis of the "Dir" output;	
$\delta_{ m DIR}$	25		$(0-25.5^{\circ})$	0x43	in tenths of a degree
Read-Only Memory					
		R	N/A (ASCII)	0x80-x81	ASCII date code in the form
YY					YYWWXX, where:
ww XX				0x82-x83 0x84-x85	YY = year;
	N/A				WW = work week;
					XX = internal code.
					The left-most character is in address
					0x80 and the right-most in 0x85.
	$\begin{array}{c c} \theta \\ Sin\theta \\ Cos\theta \\ Dir \\ \\ \theta_{DIR} \\ \\ \theta_{0} \\ \\ m \\ \delta_{DIR} \\ \\ YY \\ WW \\ \\ \end{array}$	$\begin{array}{c c} \theta \\ Sin\theta \\ Cos\theta \\ \end{array} \begin{array}{c c} N/A \\ Dir \\ \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $

Table 1. ASR002 Memory Locations.





# Power-Up and Initialization

# Absolute position

Unlike some encoder types, ASR002 sensors detect absolute position and maintain position information when the power is removed. The sensor powers up indicating the correct position.

### Nonvolatile parameters

All parameters are nonvolatile so they can be set once (via SPI), and remain for the life of the product if desired.

# **Minimizing Magnetic Interference**

Several precautions can be taken for applications requiring the best accuracy to avoid distorting the magnetic field at the sensor:

- Components such as resistors and capacitors are generally slightly magnetic, and should be located at least several millimeters from the sensor.
- If components must be located near the sensor, ultrasmall components such as 0201 (0603 metric) contain less ferromagnetic material than larger components.
- Nonmagnetic resistors and capacitors can be used for extremely sensitive applications. A nonmagnetic 0.1 μF bypass capacitor can be used close the sensor, with a conventional 10 μF ceramic capacitor at least several millimeters away.

#### **Minimizing Noise**

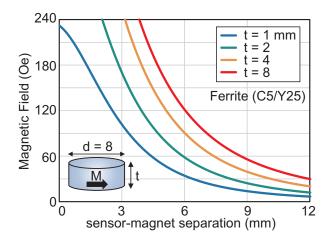
Several steps minimize noise:

- Inadequate bypassing can cause noise or anomalous device behavior.  $10 \,\mu\text{F}$  total bypass capacitance is recommended. To minimize magnetic field disruption, a small (e.g., 0201 / 0603 metric)  $0.1 \,\mu\text{F}$  ceramic capacitor can be placed as close as possible to the  $V_{DD}$  and GND pins with a  $10 \,\mu\text{F}$  ceramic capacitor a few millimeters away. The small capacitors contain very little ferromagnetic material.
- Use a circuit board ground plane.
- If the sensor is not being used for current over trace sensing, ground the sensor's center pad so the leadframe acts as a shield.



### **Magnet Selection**

The sensor's wide operating field range of 6 to 20 mT (60 to 200 Oe) allows inexpensive magnets and operation over a wide range of magnet spacing. The figures below show the magnetic field for various magnet geometries and distances for inexpensive C5/Y25 grade ferrite magnets:



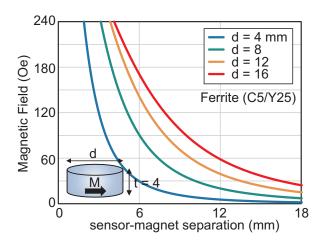


Figure 8. Magnetic fields for various geometries of C5/Y25 ferrite magnets plotted for the distance between the magnet and sensor. Eight-millimeter diameter magnets of various thicknesses are shown at left, and four-millimeter thick magnets of various diameters are shown at right.

Field varies less with distance for larger magnets, so maximizing magnet size within the mechanical constraints of the system maximizes accuracy.

Higher-grade magnets can be used for high-temperature applications or large magnet-sensor separations. The graph below shows field strengths with various materials:

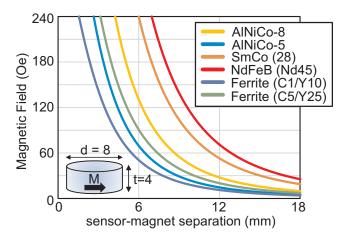


Figure 9. Magnetic fields from an 8 millimeter diameter, 4 millimeter thick magnet for increasing magnet-sensor separation. NdFeB materials produce the largest magnetic fields and separations. SmCo and AlNiCo materials offer the highest operating temperatures. Ferrite magnets are the most cost-effective.

Our free Web app can be used to determine optimum separations for various magnet sizes and materials: <a href="https://www.nve.com/spec/calculators.php">https://www.nve.com/spec/calculators.php</a>.

NVE's Online Store stocks popular magnets.



# **Application Circuits**

# Typical Microcontrollers Interface

A typical microcontroller interface is shown below:

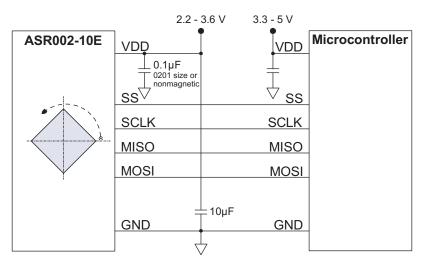


Figure 10. Typical microcontroller interface.

The ASR002 is configured as a Slave and the microcontroller should be configured as the Master. The ASR002 SPI interface is compatible with 3.3 or five-volt microcontrollers.



## Typical Read and Write Communications Pseudocode

```
//SPI clock set elsewhere (2 MHz max.)
//SPSR = SPI Status Register; SPIF = SPI Status Register Interrupt flag
//SS set low (active) elsewhere
      {
      case COMM_GET_MEM:
                                 //Routine to READ memory
                                 //Sends the address to read from
SPDR=buffer[1];
while(! (SPSR & (1<<SPIF)));
                                 //Waits for transmission
_delay_us(3);
                                 //Allow 3 microseconds between address bytes
SPDR=0x00;
                                 //'0' for second address byte (indicates read)
while(! (SPSR & (1<<SPIF)));
                                 //Waits for transmission
_delay_us(10);
                                 //Allows 10 microseconds for the address to be sent
SPDR=0x00;
while(! (SPSR & (1<<SPIF)));
                                //Waits for transmission to complete
                                 //Allows 10 microseconds for data to be sent
_delay_us(10);
                                 //Reads the first byte of data (MSB)
MSB=SPDR;
SPDR=0x00;
while(!(SPSR & (1<<SPIF)));
_delay_us(10);
                                 //Allows 10 microseconds for data to be sent
                                 //Reads the second byte of data (LSB)
LSB=SPDR;
                                 //Stores data in the buffer
buffer[0]=MSB;
buffer[1]=LSB;
*output_len=2;
                                 //Number of bytes to transmit
break;
      case COMM_SET_MEM:
                                 //WRITE memory routine (to set sensor parameters)
                                 //Puts the address to read from in the buffer
SPDR=buffer[1];
while(! (SPSR & (1<<SPIF)));
                                 //Wait for transmission to be complete
                                 //Allow address byte to be sent
_delay_us(3);
SPDR=0x01;
                                 //'1' for second address byte (write bit)
                                 //Wait for transmission to complete
while(! (SPSR & (1<<SPIF)));
_delay_us(10);
                                 //Allows time for data to be sent
                                 //Read first data byte(MSB)
SPDR=buffer[2];
while(! (SPSR & (1<<SPIF)));
                                 //Allows time for the data to be sent
_delay_us(10);
SPDR=buffer[3];
                                 //Read second data byte(LSB)
while(! (SPSR & (1<<SPIF)));
delay ms(20);
                                 //Allows 20 MILLIseconds to write to nonvolatile memory
break;
```



# **Illustrative Arduino Code for Continuous Read**

```
/****************************
Continuously read the angle from an NVE ASR002 Smart Angle Sensor
Arduino Uno connections: pin 10=SS; pin 11=MOSI; pin 12=MISO; pin 13=SCLK
******************************
#include <SPI.h>
int angle;
void setup() {
pinMode(10, OUTPUT); //Pin 10 = Sensor SS
SPI.begin ();
//Set clock rate at 2 Mbits/s; MSB first; Mode 0
SPI.beginTransaction(SPISettings(2000000, MSBFIRST, SPI_MODE0));
digitalWrite(CS, HIGH); //Disable to reset the sensor
digitalWrite(10, LOW); //Re-enable sensor
}
void loop() {
angle = (SPI.transfer (0)) << 8; // Send 0 for address angle; receive angle MSB</pre>
delayMicroseconds (3); //Allow 3 us between address bytes
angle |= SPI.transfer (0); //2nd address byte (0 for read); receive angle LSB
delayMicroseconds (10); //Allow 10 us for next data
}
```



#### Illustrative Arduino Code to Zero the Sensor

```
/******************************
Zeros an ASR002 at its current location to establish a "home position."
Arduino Uno connections: pin 11=MOSI; pin 12=MISO; pin 13=SCLK; pins 9 & 10=SS
Includes a simple procedure to read the angle.
#include <SPI.h>
int angle;
void setup() {
pinMode(10, OUTPUT); //Pin 10 = Sensor SS
SPI.begin ();
//Set clock rate to 2 Mbits/s; MSB first; Mode 0
SPI.beginTransaction(SPISettings(2000000, MSBFIRST, SPI_MODE0));
digitalWrite(10, HIGH); //Disable to reset the sensor
digitalWrite(10, LOW); //Re-enable sensor
//Read starting angle
SPI.transfer (0); //Send 0 for address angle to read starting angle
delayMicroseconds (3); //Allow 3 us between address bytes
angle = (SPI.transfer (0x41)) << 8; Read starting angle MSB and point to offset address
delayMicroseconds (3); //Allow 3 us between address bytes
angle |= SPI.transfer (1); //Read angle LSB; 2nd address byte = 1 for write
delayMicroseconds (10); //Allow 10 us for next data
//Reset offset
SPI.transfer (0); //Write offset MSB
delayMicroseconds (3); //Allow time between bytes
SPI.transfer (0); //Write offset LSB
delay (20); //20 ms NVM delay
//Write measured angle to offset parameter to zero the sensor
angle=getAngle(); //Read angle now that offset has been set to zero
SPI.transfer (0x41); //Point to offset address
delayMicroseconds (3); //Allow time between address bytes
SPI.transfer (1); //2nd address byte = 1 for write
delayMicroseconds (10);
SPI.transfer (0x41); //Write to offset parameter to zero the sensor
delayMicroseconds (3);
SPI.transfer (angle & 0xFF); //Write LSB
delay (20); //20 ms NVM delay
void loop() {}
//Procedure to read the angle
int getAngle(){
int angle;
angle = (SPI.transfer (0)) << 8; //Send 0 for address angle; receive angle MSB
delayMicroseconds (3); //Allow 3 us between address bytes
angle |= SPI.transfer (0); //2nd address byte (0 for read); receive angle LSB
delayMicroseconds (10); //Allow 10 us for next data
return angle;
}
```



# In Case of Difficulty

# Random data, or measured angles outside the allowable 0 to 3600 range.

- The SPI clock may be too fast (the ASR002 maximum clock rate is specified as 2 Mbits/s).
- Ensure the Master is operating in the correct mode (Mode 0).

# Random data, or measured angles outside the allowable 0 to 3600 range on the first readings after the sensor is selected.

The sensor is reset on a falling edge of SS. Toggling SS HIGH, then LOW will ensure the sensor is reset.

# MSB/LSB bytes are reversed.

The MSB should be read first. SPI devices use different byte orders, but the ASR002 follows the most common convention of MSB first.

# Angle data is shifted by one or more bits.

This is usually because the sensor has not completed internal shifting of bits into the correct positions. Ensure there is enough settling time between writing the address and reading the data (10 µs minimum).

#### Garbled data on first startup of Master.

Data can be left in the sensor if the Master microcontroller is reset and the sensor is not. This can be corrected by doing a "dummy read" as part of the microcontroller startup sequence, or toggling SS HIGH then LOW to reset the sensor.

## Parameters do not appear to be written correctly.

- Ensure that the Write bit is set in the second (LSB), i.e., the second address byte is a "1."
- Ensure there is adequate settling time before reading or using a written parameter (10 milliseconds minimum). Parameters are stored in nonvolatile memory, not RAM, and writing to nonvolatile memory is much slower.

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# **Evaluation Support**

### **Breakout Board**

The AG957-07E breakout board provides easy connections to an ASR002-10E angle sensor with a six pin connector. It also has a recommended 1 µF bypass capacitor:



Figure 11. AG957-07E breakout board (actual size)

0.5" x 0.6" (12 mm x 15 mm)

#### **Smart Angle Sensor Evaluation Kit**

This simple board includes an ASR002-10E Smart Angle Sensor, a microcontroller that interfaces to the Sensor via SPI, and to a PC via USB. The kit includes a diametrically-magnetized cylindrical horseshoe magnet and fixturing. A PC-based user interface provides two-way communication with the sensor to display the sensor outputs and change the sensor's parameters.



Figure 12. AG956-07E: Smart Angle Sensor Evaluation Kit.

#### **Socket Board**

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The AG954-07E provides a TDFN6 socket for easy interface to sensors such as the ASR002-10E without soldering:





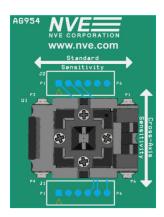


Figure 13. AG954-07E: TDFN socket board 1.5" x 2" (38 mm x 50 mm)(actual size)



### Magnets

NVE stocks five popular magnets for use with its angle sensors:

NVE Part Number	Compatible Magnet Holder	Diameter (mm)	Length (mm)	Typ. sensor distance (mm; 12 mT/120 Oe nom. field)	Material and Configuration
12526	4 mm	4	4	3	
12249	N/A	12.5	3.5	4	C5/Y25 ferrite
12527	8 mm	8	4	5	disk magnets
12528	8 mm	8	8	6	
12426*	N/A	11	11	8	Alnico-5 round horseshoe magnet with mounting hole

<sup>\*</sup>Included in the AG956-07E Smart Angle Sensor Evaluation Kit.

Table 2. Popular magnets for angle sensing.

#### **Magnet Holders**

NVE offers two magnet holders for evaluation and prototyping. The holders are machined aluminum. Set screws secure the magnets in the holders and allow magnet position adjustments. There are threaded mounting holes for a thumbscrew to turn the magnet, or the hole can be used to attach the holder to a rotating shaft. A "clockhand" indicator helps track magnet rotation:

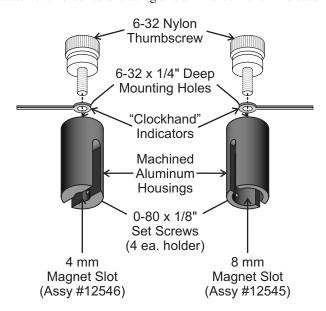


Figure 14. 4 mm magnet holder (part #12546; left) and 8 mm magnet holder (part #12545; right). 0.44" dia. x 0.88" tall (11 mm x 22 mm) outside dimensions; actual size).

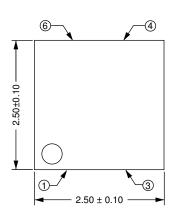
The holders are compatible with several popular diametrically-magnetized disk magnets and can be used in the AG956-07E Evaluation Kit:

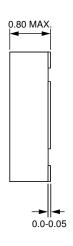
Holder		Compatible	Magnet	Max. Magnet
Part	Outside	Magnets	Diameter	Length
Number	Dimensions	(NVE part #s)	(mm)	(mm)
12546	11 mm dia. x	12526	4	4
12545	22 mm tall	12527; 12528	8	8

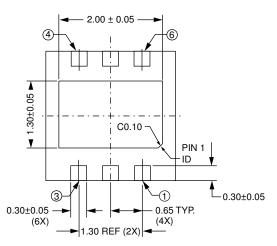
Table 3. Magnet holders.

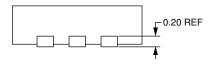


# 2.5 x 2.5 mm TDFN6 Package









Pad	Symbol	Description
1	GND	Ground/V <sub>ss</sub>
2	SCLK	SPI Clock Input
3	MISO	Sensor SPI Data Output
4	VDD	Power Supply (bypass with a 1µF capacitor)
5	MOSI	Sensor SPI Data Input
6	SS	Sensor Select Input (low to select)
Center		Internal leadframe connection; connect to GND to minimize noise.
pad		internal leadifable connection, connect to GND to minimize hoise.

# **Notes:**

- Dimensions in millimeters.
- Soldering profile per JEDEC J-STD-020C, MSL 1.





# **Ordering Information**

# ASR002 - 10E TR13

# **Product Family**

ASR = Smart Angle Sensors

# **Base Part Number**

002 = High speed, medium accuracy

# Field Range Identifier

Blank = General Purpose (6 to 20 mT / 60 to 200 Oe)

# **Part Package**

10E = RoHS-Compliant 2.5 x 2.5 mm TDFN6 Package

# **Bulk Packaging**

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TR13 = 13" Tape and Reel Package





## **Revision History**

#### SB-00-081-K

September 2019

# Change

- More specifics on bypass capacitors (p. 10).
- Added bypass capacitor details to microcontroller application circuit. (p. 12).

• Clarified lot code formatting and corrected its memory address range (p. 9).

Added second bypass capacitor to breakout board (p. 17).

#### SB-00-081-J Change

- Added Absolute Maximum output current specification (p. 2).
- Offering a breakout board instead of a bare board (p. 17).

#### SB-00-081-I Change

July 2019

#### SB-00-081-H Change

June 2019

August 2019

- Noted 17.5 mT (175 Oe) factory calibration field (p. 4, Note 1).
- Clarified two-byte and four-byte SPI read and write sequences (p. 8).
- Corrected default filter memory setting (p. 9).

#### SB-00-081-G Change

June 2019

Feb. 2019

Feb. 2019

Jan. 2019

SB-00-081-D

SB-00-081-C

• Added SI units (tesla) in addition to CGS (oersteds).

Changed Operating Specification "RAM Timing" from maximums to minimums.

#### SB-00-081-F Change

April 2019 • Recommend 1 µF bypass capacitor.

#### SB-00-081-E Change

- Improved "Magnet Selection" section.
- Added magnet and magnet holder information (p. 18).

# Change

• Added details on center pad and grounding recommendation to minimize noise.

# Change

- Faster RAM timing.
- Reduced data transfer rate from 2.5 to 2 Mbits/s for more design margin.
- Corrected number of bits in angular offset.
- Added Arduino code to zero the Sensor.
- Added "In Case of Difficulty" section.
- Dropped daisy-chained SPI application diagram (not supported).
- Added AG954-07E socket board.
- Typographic and cosmetic changes.

#### Change SB-00-081-B

Jan. 2019

• Added typical communications pseudocode.

# SB-00-081-A

Jan. 2019

### Change

- Expanded and updated SPI timing specifications.
- Added detailed SPI timing diagrams.
- Tightened typ. supply current specification to 4 mA.
- Revised minimum operating field to 60 Oe.
- Added sensor direction output and hysteresis parameter.
- Added raw Sin and Cos vector outputs.
- Added illustrative microcontroller code.
- Finalized pinout.
- Added evaluation kit and board.
- Dropped customer calibration capability (unnecessary).

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• Various typographic corrections.

#### Change **SB-00-081-PRELIM**

Preliminary release.





Oct. 2018





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